TOSHIBA Diode Silicon Epitaxial Planar Type

# HN2D01F

### **Ultra High Speed Switching Application**

HN2D01F is composed of 3 independent diodes.

• Low forward voltage  $: V_{F(3)} = 0.98V \text{ (typ.)}$ 

• Fast reverse recovery time:  $t_{rr} = 1.6ns$  (typ.)

• Small total capacitance :  $CT = 0.5\mu F$  (typ.)

#### Absolute Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Maximum (peak) reverse Voltage	$V_{RM}$	85	V
Reverse voltage	$V_{R}$	80	>
Maximum (peak) forward current	I <sub>FM</sub>	240 (*)	mA
Average forward current	IO	80 (*)	mA
Surge current (10ms)	I <sub>FSM</sub>	1 (*)	Α
Power dissipation	Р	300	mW
Junction temperature	Tj	125	°C
Storage temperature range	T <sub>stg</sub>	-55~125	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the

reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

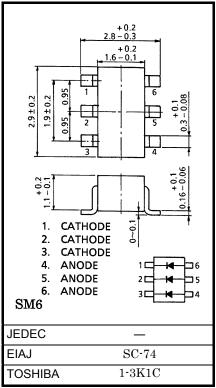
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

(\*) This is absolute maximum rating of single diode (Q1 or Q2 or Q3). In the case of using 2 ro 3 diodes, the absolute maximum ratings per diodes is 75 %f the single diode one.

## Electrical Characteristics (Q1, Q2, Q3 Common Ta = 25°C)

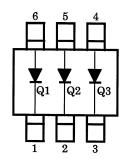
Characteristic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit	
Forward voltage	V <sub>F (1)</sub>	_	I <sub>F</sub> = 1mA	_	0.62	_		
	V <sub>F (2)</sub>	_	I <sub>F</sub> = 10mA	1	0.75	_	٧	
	V <sub>F (3)</sub>	_	I <sub>F</sub> = 100mA	_	0.98	1.20		
Reverse current	I <sub>R (1)</sub>	_	V <sub>R</sub> = 30V	_	_	0.1	•	
	I <sub>R (2)</sub>	_	V <sub>R</sub> = 80V	_	_	0.5	μA	
Total capacitance	C <sub>T</sub>	_	V <sub>R</sub> = 0, f = 1MH <sub>z</sub>	ı	0.5	3.0	pF	
Reverse recovery time	t <sub>rr</sub>	_	I <sub>F</sub> = 10mA (Fig.1)		1.6	4.0	ns	

Unit in mm

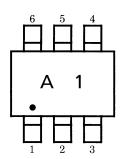


Weight: 0.015g

## Pin Assignment (Top View)

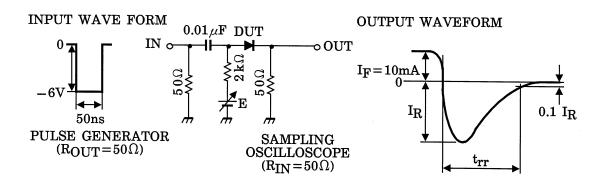


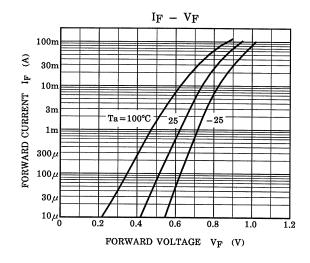
## Marking

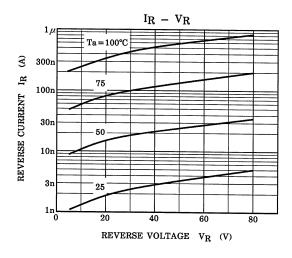


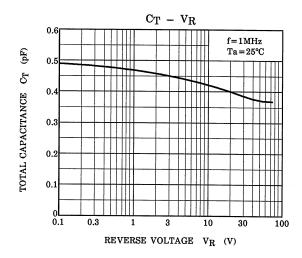
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Fig.1 Reverse Recovery Time (trr) Test Circuit









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20070701-EN GENERAL

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